NSN 5961-00-103-7667

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-103-7667 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage, dc and 60.0 collector to emitter voltage/static/base open and 100.0 collector to emitter reverse voltage, with base short-circuited to emitter and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 1.17 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 88818-g181-725 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No